

Technical Data Sheet

Side Looking Silicon PIN Photodiode

PT57-21B/TR8

Features

- Fast response time
- High photo sensitivity
- Small junction capacitance
- Compatible with infrared and vapor phase reflow solder process.
- Pb free
- The product itself will remain within RoHS compliant version.



• PT57-21B/TR8 is a high speed silicon NPN epitaxial planar phototransistor in a compact surface-mountable package. It's compatible with automatic placement equipment and can withstand IR reflow, vapor phase reflow, and wave solder processes.

Applications

- Miniature switch
- Counters and sorter
- Position sensor
- Infrared applied system

Device Selection Guide

LifecyclePhase:正式發行

LED Part No.	Chip	Lens Color	
LED Part No.	Material	Lens Color	
PT57-21B/TR8	Silicon	Black	

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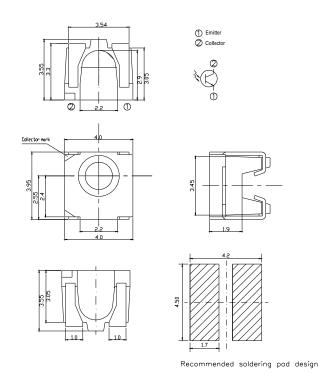
Device No: DIR-0000252 Prepared date: 09-08-2010 Prepared by: Daniel Yang
Revision: 2 Release Date: 2010-09-10 13:21:48.0

Expired Period: Forever





Package Dimensions



Notes: 1.All dimensions are in millimeters

2.Tolerances unless dimensions ±0.1mm

Absolute Maximum Ratings (Ta=25)

Parameter	Symbol	Rating	Unit	
Collector-Emitter Voltage	V_{CEO}	30	V	
Emitter-Collector-Voltage	V_{ECO}	5	V	
Collector Current	I_{C}	20	mA	
Operating Temperature	T_{opr}	-25 ~ +85		
Storage Temperature	T_{stg}	-40 ~ +85		
Soldering Temperature	T_{sol}	260		
Power Dissipation at(or below)	P _c	75	mW	
25 Free Air Temperature				

Notes: *1:Soldering time 5 seconds.

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Electro-Optical Characteristics (Ta=25)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Rang Of Spectral Bandwidth	0.5		700		1100	nm
Wavelength Of Peak Sensitivity	Р			940		nm
Collector-Emitter Breakdown Voltage	$\mathrm{BV}_{\mathrm{CEO}}$	$I_C=100 \mu A$ $Ee=0mW/cm^2$	30			V
Emitter-Collector Breakdown Voltage	BV _{ECO}	$I_E=100 \mu A$ $Ee=0 mW/cm^2$	5			V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =0.1mA Ee=1m W/cm ²			0.4	V
Collector Dark Current	I_{CEO}	V _{CE} =20V Ee=0mW/cm ²			100	nA
On State Collector Current	$I_{C(ON)}$	$V_{CE}=5V$ $Ee=1mW/cm^2$	0.4	0.8	1	mA
Rise Time	$t_{\rm r}$	V _{CE} =5V	-29	15	100	μS
Fall Time	t_{f}	I _C =1mA R _L =1000		15		

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Typical Electro-Optical Characteristics Curves

Fig.1Collector Power Dissipation vs.

Ambient Temperature

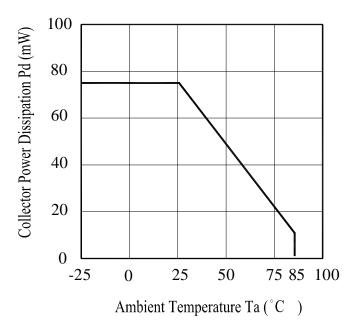


Fig.3 Relative Collector Current vs.

Ambient Temperature

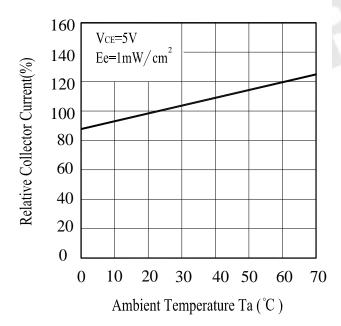


Fig.2 Spectral Sensitivity

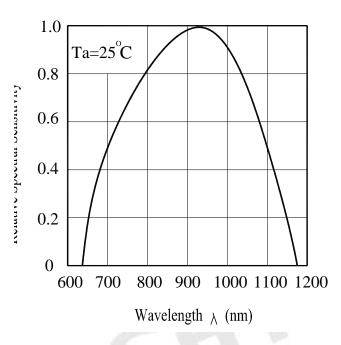
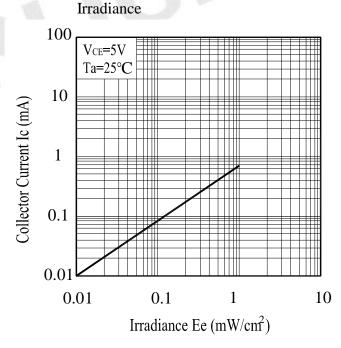


Fig.4 Collector Current vs.



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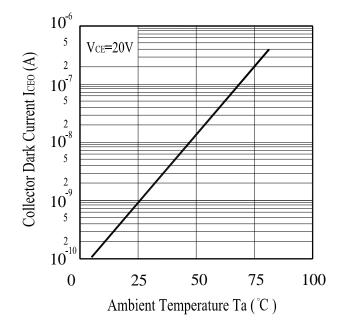
Expired Period: Forever



Typical Electro-Optical Characteristics Curves

Fig.5 Collector Dark Current vs.

Ambient Temperature



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Precautions For Use

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

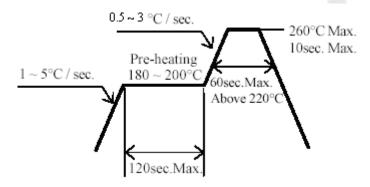
- 2. Storage
 - 2.1 Do not open moisture proof bag before the products are ready to use.
 - 2.2 Before opening the package, the LEDs should be kept at 30 or less and 90% RH or less.
 - 2.3 The LEDs should be used within a year.
 - 2.4 After opening the package, the LEDs should be kept at 30 or less and 70%RH or less.
- 2.5 The LEDs should be used within 168 hours (7 days) after opening the package.
- 2.6 If the moisture absorbent material (silica gel) has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the following conditions.

Baking treatment : 60±5 for 24 hours.

3. Soldering Condition

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3.1 Pb-free solder temperature profile



- 3.2 Reflow soldering should not be done more than two times.
- 3.3 When soldering, do not put stress on the LEDs during heating.

3.4 After soldering, do not warp the circuit board.

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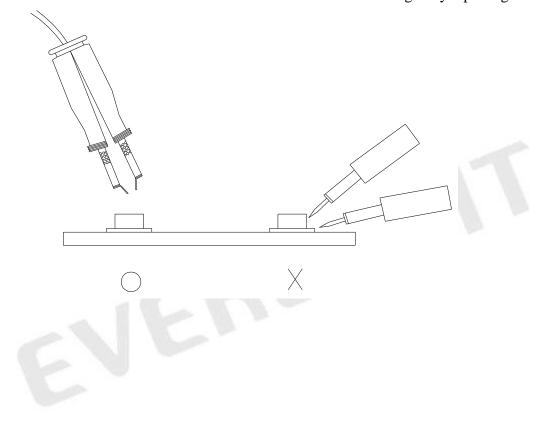


4. Soldering Iron

Each terminal is to go to the tip of soldering iron temperature less than 350 for 3 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

5.Repairing

Repair should not be done after the LEDs have been soldered. When repairing is unavoidable, a double-head soldering iron should be used (as below figure). It should be confirmed beforehand whether the characteristics of the LEDs will or will not be damaged by repairing.

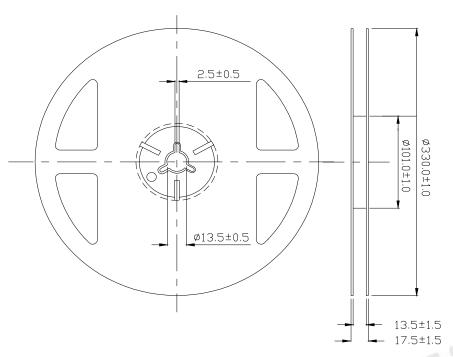


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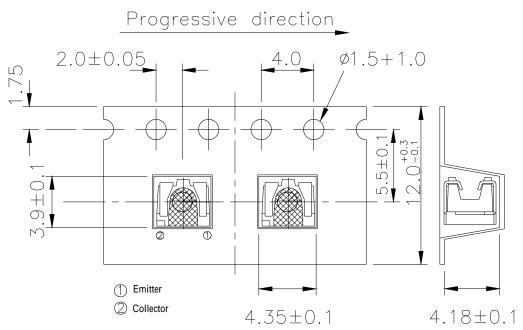
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Package Dimensions



Note: The tolerances unless mentioned is ±0.1mm ,Unit = mm **Carrier Tape Dimensions:** Loaded quantity 500 PCS per reel



Unit:mm

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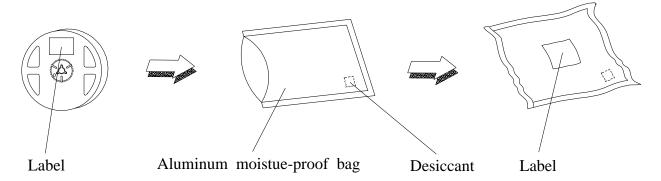
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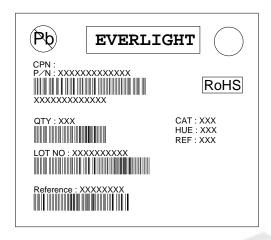
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Packing Procedure



Label Form Specification



CPN: Customer's Production Number

P/N : Production Number QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

MADE IN TAIWAN: Production Place

Notes

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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